

| | Page |
|--|------|
| Summary of Types | 9 |
| Symbols and Terms | 18 |
| Technical Explanations | 21 |
| 1 General | 22 |
| 2 Detectors (Radiant-sensitive components) | 23 |
| 2.1 Charge carrier generation in a photodiode | 23 |
| 2.2 Detectors | 25 |
| 2.2.1 Spectral sensitivity | 25 |
| 2.2.2 Photodiodes (PN and PIN diodes) | 26 |
| 2.2.3 Photovoltaic cells | 27 |
| 2.2.4 Phototransistors | 28 |
| 3 Emitters | 29 |
| 3.1 Light emitting diodes (IREDs) | 29 |
| 3.1.1 Definitions | 29 |
| 3.1.2 Principle of operation and materials | 30 |
| 3.1.3 IR emitters (IREDs) | 31 |
| 3.1.4 Electrical and optical characteristics of IREDs | 33 |
| 4 Measuring technique | 35 |
| 4.1 Detectors | 35 |
| 4.1.1 Setting of color temperature | 36 |
| 4.1.2 Setting the standard lamp | 36 |
| 4.1.3 Spectral sensitivity | 37 |
| 4.1.4 Solid angle | 38 |
| 4.1.5 Short-circuit current | 38 |
| 4.1.6 Switching times | 39 |
| 4.2 Emitters | 40 |
| 4.2.1 Radiation in the infrared range (IRED) | 40 |
| 4.2.2 Measuring the radiant intensity of narrow-beam IR emitters | 41 |
| 4.2.3 Measurement of switching times | 45 |
| 5 Terms, definitions, standards | 46 |
| 5.1 Terms of temperature for optical radiations | 46 |
| 5.2 Radiation and light measurements | 48 |
| 5.3 Radiation characteristics | 50 |
| 5.4 Illuminance | 52 |
| 5.5 Luminous density | 56 |
| 5.6 Electromagnetic radiation | 58 |
| 6 Delivery quality (AQL) | 60 |
| 7 Mounting and soldering instructions | 61 |
| 7.1 General | 61 |

Contents

| | | |
|--|---|------------|
| 7.1.1 | Silicon photovoltaic cells and photodiodes in open design | 61 |
| 7.2 | Soldering instructions | 62 |
| 7.2.1 | Cleaning solvents | 62 |
| Photovoltaic cells | | 65 |
| Photodiodes | | 97 |
| Phototransistors | | 263 |
| Photo ICs | | 313 |
| Custom-designed optoelectronic multichip arrays (KOM) | | 321 |
| Infrared emitters (IRED) | | 331 |
| Summary of types (in alphanumerical order) | | 435 |
| Ordering codes | | 437 |
| Siemens worldwide (addresses) | | 439 |